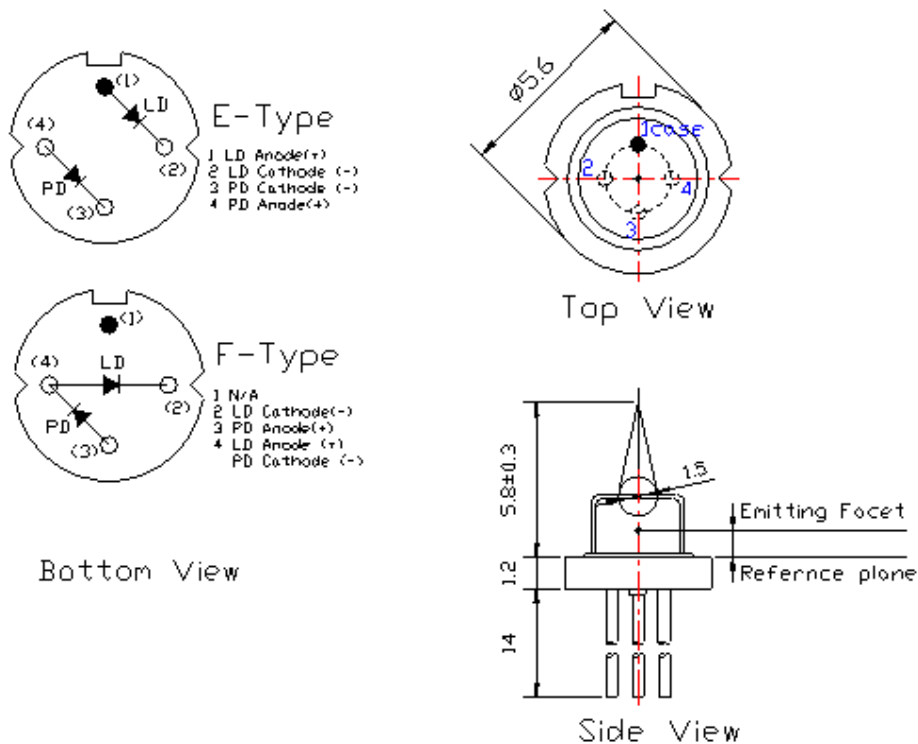


1310nm Laser Diode

LCU130582E/F

- Features
 - Un-cooled Laser diode with MQW structure
 - Wide operation temperature range
 - Dew point below -40°C
 - Both ball lens and flat window cap available

■ External dimensions (Unit : mm)



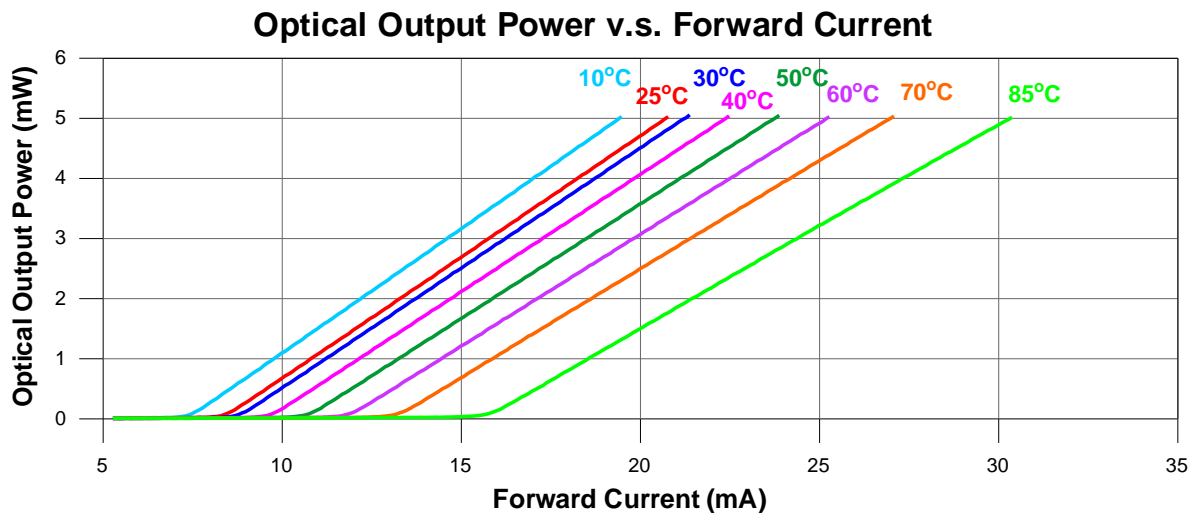
■ Absolute Maximum Ratings(Tc=25°C)

Characteristic	Symbol	Rating	Unit
Optical Output Power	P _o	5	mW
LD Reverse Voltage	V _r (LD)	2	V
PD Reverse Voltage	V _r (PD)	10	V
Operation Case Temperature	Top	-40 ~ +85	°C
Storage Temperature	T _{stg}	-40 ~ +125	°C

1310nm Laser Diode**Electrical and Optical Characteristics(Tc=25°C)**

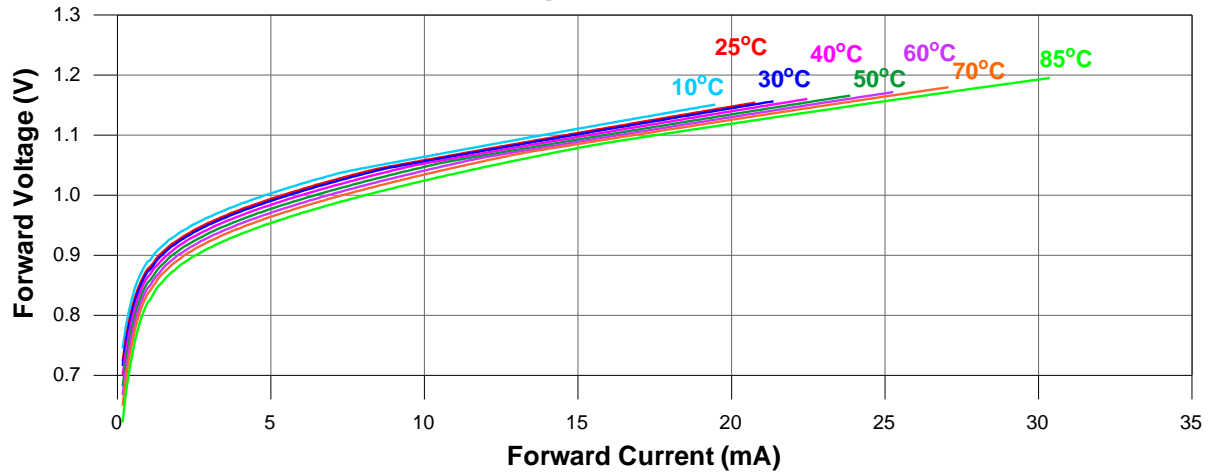
Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit	
Threshold Current	I _{th}	T _c = 25°C	-	8	15	mA	
Threshold Current	I _{th}	T _c = -40 ~ +85°C	-	16	45	mA	
Operating Current	I _{op}	P _o =5mW	-	21	28	mA	
Operating Current	I _{op}	T _c = -40 ~ +85°C	-	31	60	mA	
Operation Voltage	V _{op}	P _o = 5mW	-	1.2	1.5	V	
Slope Efficiency	SE	P _o = 1 to 4mW	0.25	0.4	-	mW/mA	
Monitor Current (PD)	I _m	P _o = 5mW, V _{RPD} =2V	0.05	0.15	-	mA	
Dark Current (PD)	I _d	V _{RPD} =5V	-	-	0.1	μA	
Capacitance (PD)	C _t	V _{RPD} =5V, f=1MHz	-	10	20	pF	
Lasing Wavelength	λ	P _o = 5mW	1290	1310	1330	nm	
Spectral Width	Δλ	P _o = 5mW	-	3	5	nm	
Optical Output Power	P _o	CW, Kink free	5	-	-	nm	
P-I Kink	K _i	P _o < 5mW	-	-	20	%	
Rise and fall time	t _r , t _f	P _o = 5mW, 10%~90%	-	-	0.7	ns	
Tracking Error	TE	P _o = 5mW, V _{RPD} =1V	-0.7	-	0.7	dB	
Beam Divergence (FWHM)	Parallel	θ //	P _o = 5mW	-	8	-	deg.
	Perpendicular	θ ⊥	P _o = 5mW	-	10	-	deg.

©θ // and θ ⊥ are defined as the angle within which the intensity is 50% of the peak value.

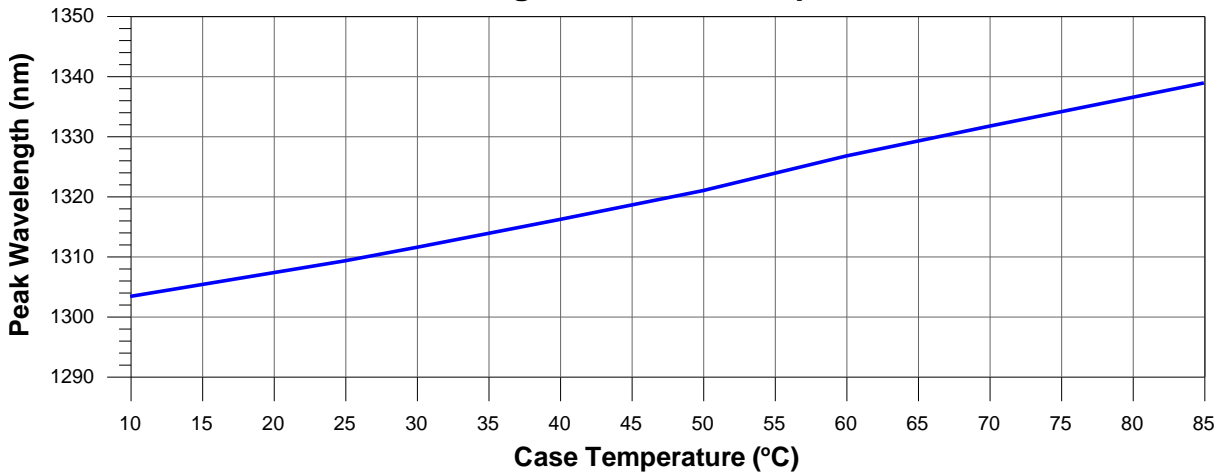
Typical characteristic curves

1310nm Laser Diode

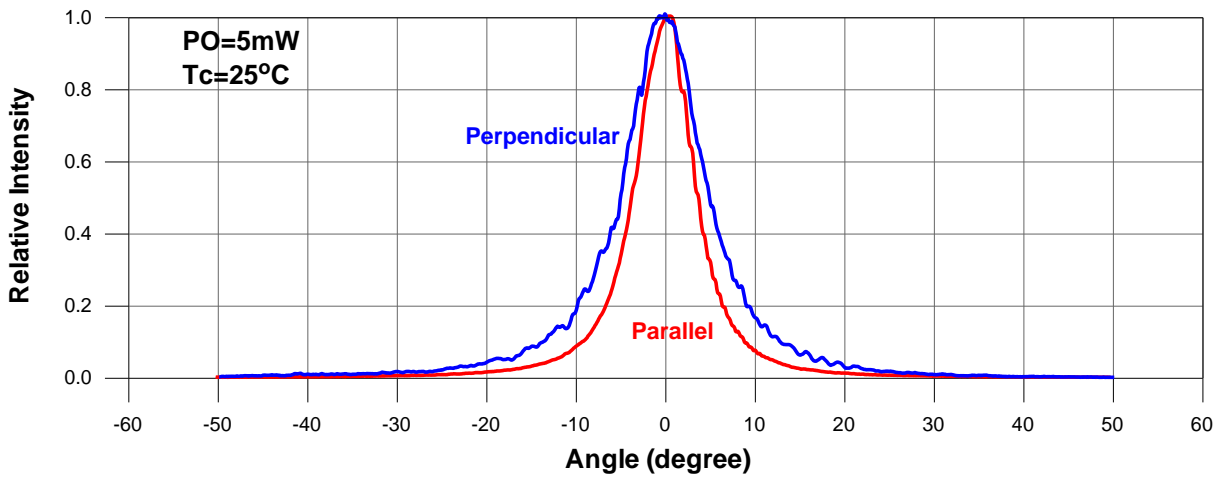
Forward Voltage v.s. Forward Current



Peak Wavelength v.s. Case Temperature

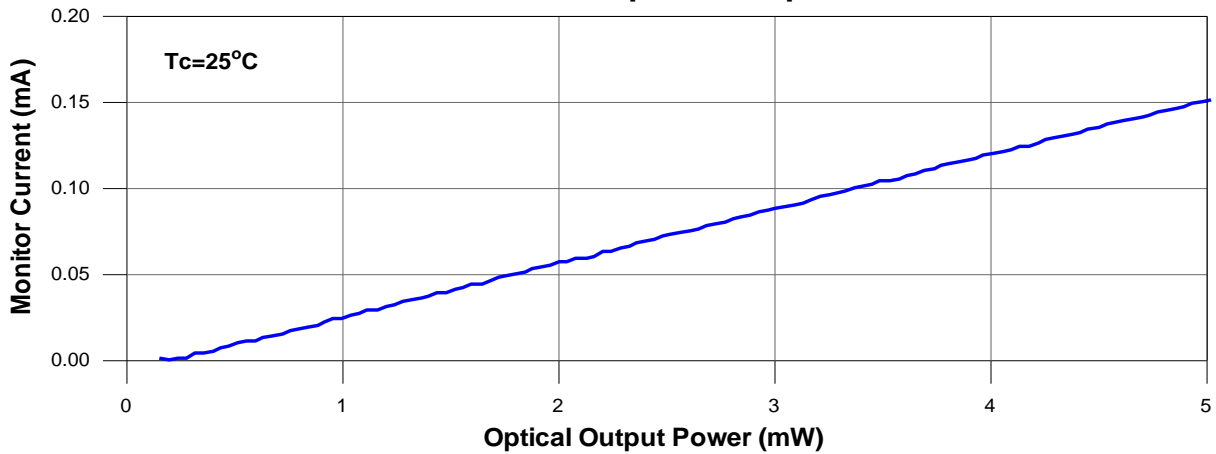


Far-Field Pattern

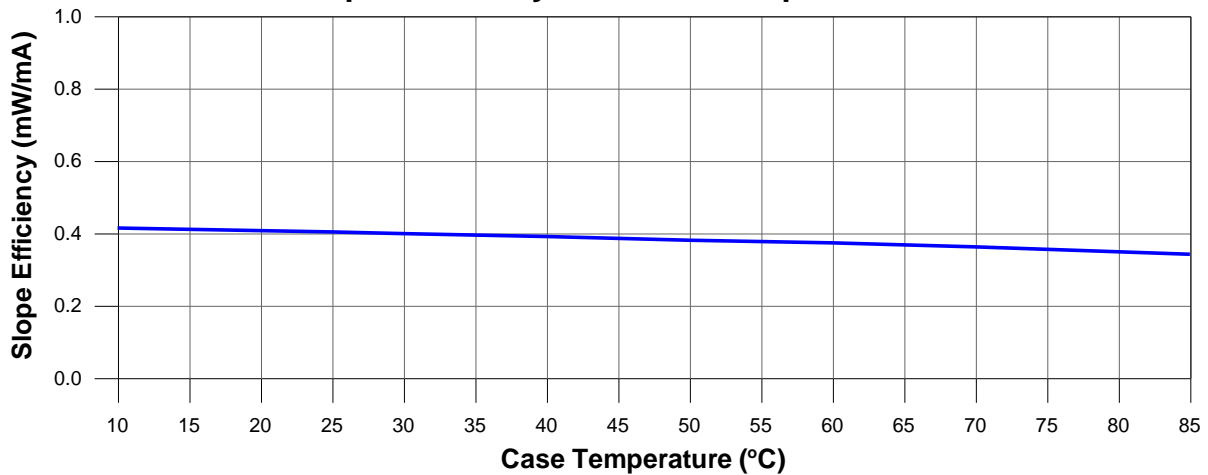


1310nm Laser Diode

Monitor Current v.s. Optical Output Power



Slope Efficiency v.s. Case Temperature



Threshold Current v.s. Case Temperature

